

ISC Silicon NPN Power Transistor

2SC3989

DESCRIPTION

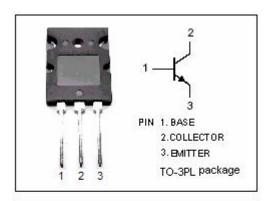
- · High Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 500V(Min)
- · High Switching Speed
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

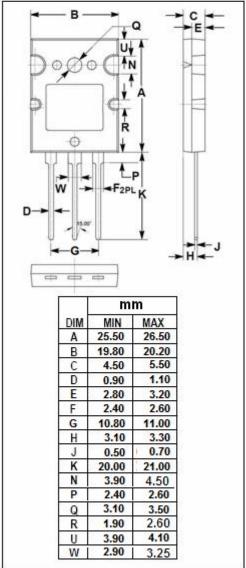
APPLICATIONS

· Designed for switching regulator and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{СВО}	Collector-Base Voltage	800	V	
V _{CEO}	Collector-Emitter Voltage	500	V	
V _{EBO}	Emitter-Base voltage		V	
Ic	Collector Current-Continuous 25		Α	
Ісм	Collector Current-Peak		Α	
I _B	Base Current-Continuous	8	А	
Pc	P _C Collector Power Dissipation @ T _C =25°C		W	
TJ	Junction Temperature 150		$^{\circ}$	
T _{stg}	T _{stg} Storage Temperature Range		$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA ; I _B = 0	500			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	Ic= 1mA; I _E = 0	800			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1m A; I _C = 0	7			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 12A; I _B = 2.4A			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 12A; I _B = 2.4A			1.5	V
Ісво	Collector Cutoff Current	V _{CB} = 500V ; I _E = 0			10	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μА
h _{FE-1}	DC Current Gain	I _C = 2.4A ; V _{CE} = 5V	15		50	
h _{FE-2}	DC Current Gain	I _C = 12A ; V _{CE} = 5V	8			
f⊤	Current-Gain—Bandwidth Product	I _C = 2.4A ; V _{CE} = 10V		18		MHz
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V		260		pF

♦ h_{FE-1} Classifications

L	М	N	
15-30	20-40	30-50	

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